

4-BIT BIDIRECTIONAL UNIVERSAL SHIFT REGISTER; 3-STATE

FEATURES

- Synchronous parallel or serial operating
- 3-state outputs
- Output capability: bus driver
- ICC category: MSI

GENERAL DESCRIPTION

The 74HC/HCT40104 are high-speed Si-gate CMOS devices and are pin compatible with the "40104" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT40104 are universal shift registers featuring parallel inputs, parallel outputs, shift-right and shift-left serial inputs and 3-state outputs allowing the devices to be used in bus-organized systems.

In the parallel-load mode (S₀ and S₁ are HIGH), data is loaded into the associated flip-flop and appears at the output after the positive transition of the clock input (CP).

During loading, serial data flow is inhibited. Shift-right and shift-left are accomplished synchronously on the positive clock edge with serial data entered at the shift-right (D_{SR}) and shift-left (D_{SL}) serial inputs, respectively.

Clearing the register is accomplished by setting both mode controls (S₀ and S₁) LOW and clocking the register. When the output enable input (OE) is LOW, all outputs assume the high-impedance OFF-state (Z).

APPLICATIONS

- Arithmetic unit bus registers
- Serial/parallel conversion
- General-purpose register for bus organized systems
- General-purpose registers

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t _{PHL} / t _{PLH}	propagation delay CP to Q _n	C _L = 15 pF V _{CC} = 5 V	13	15	ns
f _{max}	maximum clock frequency		62	57	MHz
C _I	input capacitance		3.5	3.5	pF
CPD	power dissipation capacitance per package	notes 1 and 2	75	75	pF

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

Notes

1. P_D is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = CPD \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz C_L = output load capacitance in pF
f_o = output frequency in MHz V_{CC} = supply voltage in V
Σ (C_L × V_{CC}² × f_o) = sum of outputs

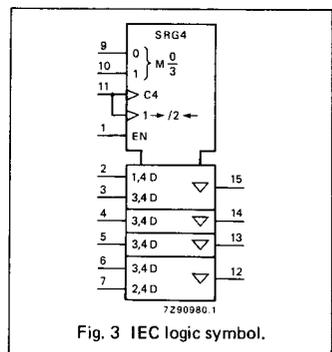
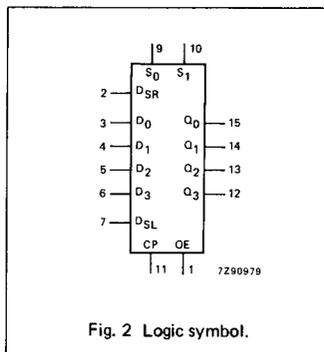
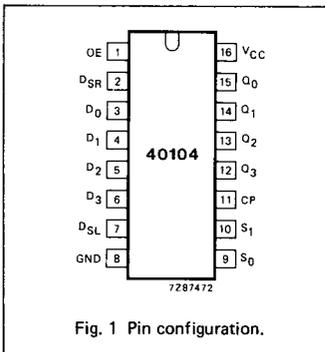
2. For HC the condition is V_I = GND to V_{CC}
For HCT the condition is V_I = GND to V_{CC} - 1.5 V

PACKAGE OUTLINES

16-lead DIL; plastic (SOT38Z).
16-lead mini-pack; plastic (SO16; SOT109A).

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	OE	3-state output enable input (active HIGH)
2	D _{SR}	serial data shift-right input
3, 4, 5, 6	D ₀ to D ₃	parallel data inputs
7	D _{SL}	serial data shift-left input
8	GND	ground (0 V)
9, 10	S ₀ , S ₁	mode control inputs
11	CP	clock input (LOW-to-HIGH, edge-triggered)
15, 14, 13, 12	Q ₀ to Q ₃	3-state parallel outputs
16	V _{CC}	positive supply voltage



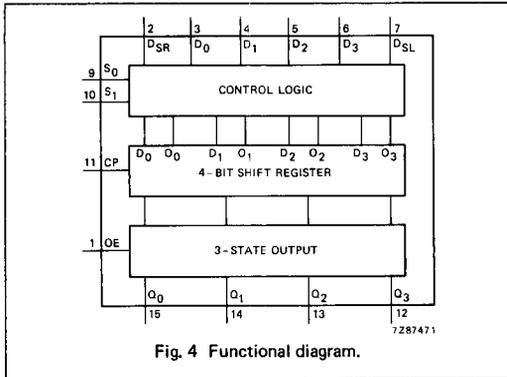


Fig. 4 Functional diagram.

FUNCTION TABLE

H = HIGH voltage level
L = LOW voltage level
X = don't care
 t_{n+1} = state after next LOW-to-HIGH transition of CP

OPERATING MODES	INPUTS (OE = HIGH)					OUTPUTS at t_{n+1}			
	S ₁	S ₀	D _{SR}	D _{SL}	D ₀ to D ₃	Q ₀	Q ₁	Q ₂	Q ₃
reset	L	L	X	X	X	L	L	L	L
shift left	H H	L L	X X	L H	X X	Q ₁ Q ₁	Q ₂ Q ₂	Q ₃ Q ₃	L H
shift right	L L	H H	L H	X X	X X	L H	Q ₀ Q ₀	Q ₁ Q ₁	Q ₂ Q ₂
parallel load	H H	H H	X X	X X	L H	L H	L H	L H	L H

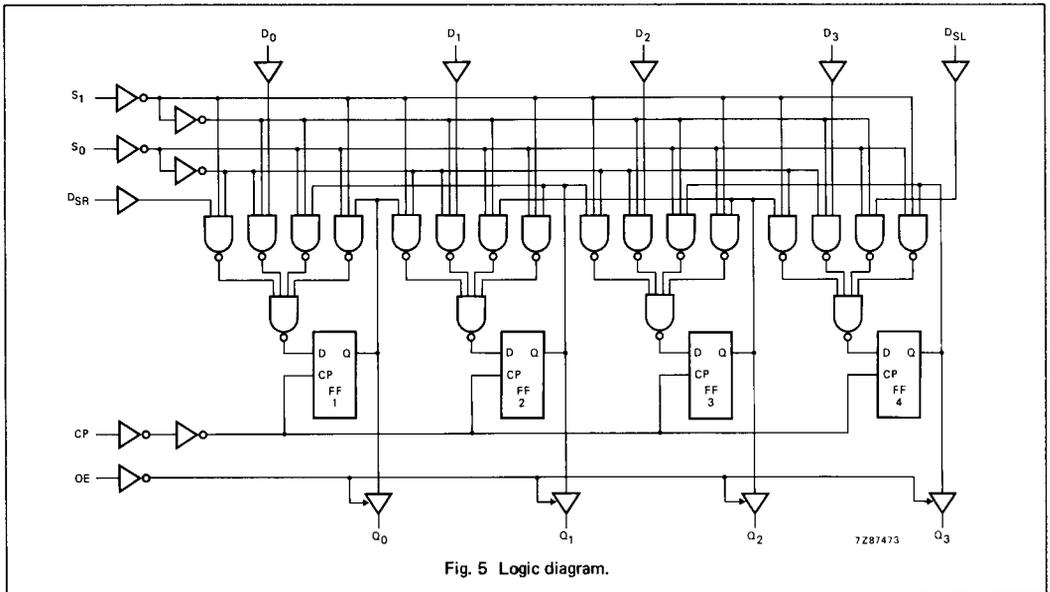


Fig. 5 Logic diagram.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver

I_{CC} category: MSI**AC CHARACTERISTICS FOR 74HC**GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS		
		74HC							V _{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t _{PHL} / t _{PLH}	propagation delay CP to Q _n		44 16 13	170 34 29		215 43 37		255 51 43	ns	2.0 4.5 6.0	Fig. 6
t _{PZH} / t _{PZL}	3-state output enable time OE to Q _n		33 12 10	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 7
t _{PHZ} / t _{PLZ}	3-state output disable time OE to Q _n		50 18 14	150 30 26		190 38 33		225 45 38	ns	2.0 4.5 6.0	Fig. 7
t _{THL} / t _{TLH}	output transition time		14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig. 6
t _W	clock pulse width HIGH or LOW	80 16 14	11 4 3		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 6
t _{su}	set-up time D _n , D _{SR} , D _{SL} to CP	80 16 14	17 6 5		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 8
t _{su}	set-up time S ₀ , S ₁ to CP	80 16 14	22 8 6		100 20 17		120 24 20		ns	2.0 4.5 6.0	Fig. 8
t _h	hold time D _n , D _{SR} , D _{SL} to CP	2 2 2	-8 -3 -2		2 2 2		2 2 2		ns	2.0 4.5 6.0	Fig. 8
t _h	hold time S ₀ , S ₁ to CP	2 2 2	-14 -5 -4		2 2 2		2 2 2		ns	2.0 4.5 6.0	Fig. 8
f _{max}	maximum clock pulse frequency	6.0 30 35	19 56 67		4.8 24 28		4.0 20 24		MHz	2.0 4.5 6.0	Fig. 6

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver

I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

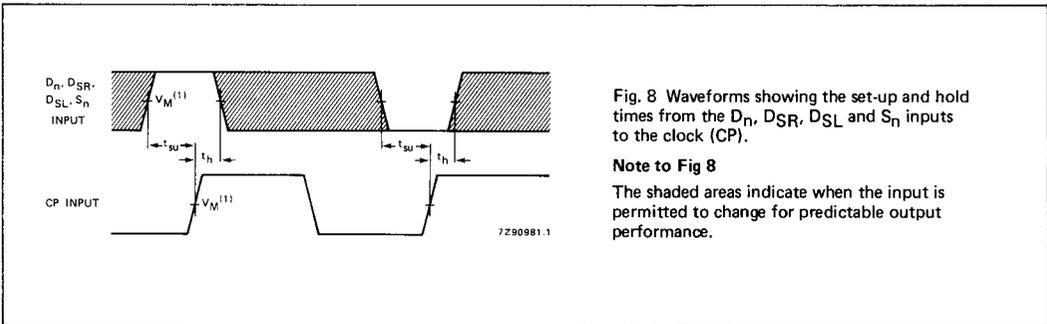
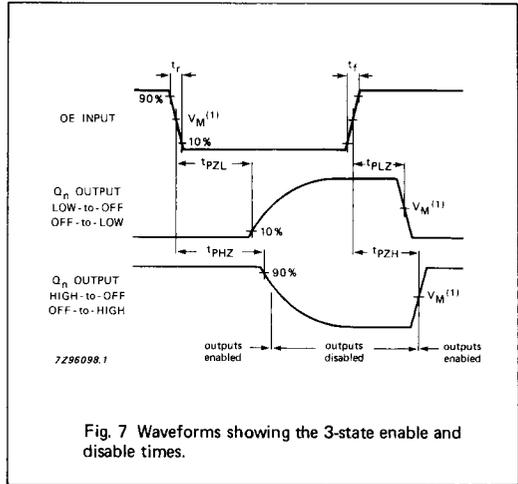
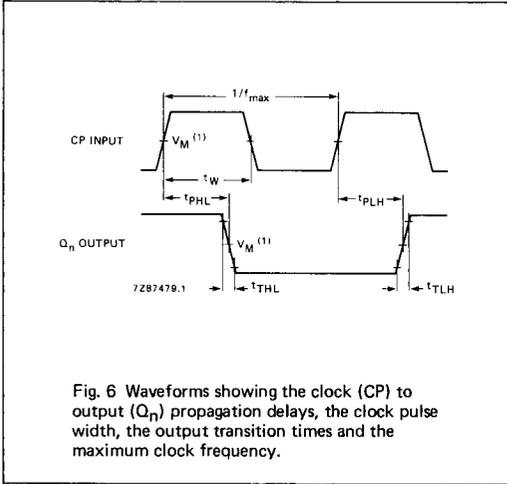
INPUT	UNIT LOAD COEFFICIENT
D ₀ to D ₃	0.35
D _{SR} , D _{SL}	0.35
CP	0.35
S ₀ , S ₁	0.70
OE	1.40

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS		
		74HCT							V _{CC} V	WAVEFORMS	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t _{PHL} / t _{PLH}	propagation delay CP to Q _n	18	34		43		51	ns	4.5	Fig. 6	
t _{PZH} / t _{PZL}	3-state output enable time OE to Q _n	12	30		38		45	ns	4.5	Fig. 7	
t _{PHZ} / t _{PLZ}	3-state output disable time OE to Q _n	21	35		44		53	ns	4.5	Fig. 7	
t _{THL} / t _{TLH}	output transition time	5	12		15		18	ns	4.5	Fig. 6	
t _W	clock pulse width HIGH or LOW	16	7		20		24	ns	4.5	Fig. 6	
t _{su}	set-up time D _n , D _{SR} , D _{SL} to CP	16	8		20		24	ns	4.5	Fig. 8	
t _{su}	set-up time S ₀ , S ₁ to CP	20	9		25		30	ns	4.5	Fig. 8	
t _h	hold time D _n , D _{SR} , D _{SL} to CP	2	-2		2		2	ns	4.5	Fig. 8	
t _h	hold time S ₀ , S ₁ to CP	2	-5		2		2	ns	4.5	Fig. 8	
f _{max}	maximum clock pulse frequency	27	52		22		18	MHz	4.5	Fig. 6	

AC WAVEFORMS



Note to AC waveforms

(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.

HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.